

## Glass Passivated Junction Fast Switching Rectifier



*Patented\**

\* Glass-plastic encapsulation technique is covered by Patent No. 3,996,602, brazed-lead assembly by Patent No. 3,930,306

**DO-204AL (DO-41)**

### FEATURES

- Superrectifier structure for high reliability condition
- Cavity-free glass-passivated junction
- Fast switching for high efficiency
- Low leakage current
- High forward surge capability
- Meets environmental standard MIL-S-19500
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



**RoHS**  
COMPLIANT

### TYPICAL APPLICATIONS

For use in fast switching rectification of power supply, inverters, converters and freewheeling diodes for consumer, automotive and telecommunication.

### MECHANICAL DATA

**Case:** DO-204AL, molded epoxy over glass body

Epoxy meets UL 94V-0 flammability rating

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

**Polarity:** Color band denotes cathode end

### PRIMARY CHARACTERISTICS

I <sub>F(AV)</sub>	1.0 A
V <sub>RRM</sub>	50 V to 600 V
I <sub>FSM</sub>	30 A
t <sub>rr</sub>	200 ns
I <sub>R</sub>	5.0 µA
V <sub>F</sub>	1.2 V
T <sub>J</sub> max.	175 °C

### MAXIMUM RATINGS (T<sub>A</sub> = 25 °C unless otherwise noted)

PARAMETER	SYMBOL	1N4933GP	1N4934GP	1N4935GP	1N4936GP	1N4937GP	UNIT
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	200	400	600	V
Maximum RMS voltage	V <sub>RMS</sub>	35	70	145	280	420	V
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	200	400	600	V
Maximum average forward rectified current 0.375" (9.5 mm) lead length at T <sub>A</sub> = 75 °C	I <sub>F(AV)</sub>			1.0			A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>			30			A
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>			- 65 to + 175			°C

# 1N4933GP thru 1N4937GP

Vishay General Semiconductor



## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

PARAMETER	TEST CONDITIONS	SYMBOL	1N4933GP	1N4934GP	1N4935GP	1N4936GP	1N4937GP	UNIT
Maximum instantaneous forward voltage	1.0 A	$V_F$		1.2				V
Maximum DC reverse current at rated DC blocking voltage		$I_R$			5.0 100			$\mu\text{A}$
Maximum reverse recovery time	$I_F = 1.0 \text{ A}$ , $V_R = 30 \text{ V}$	$t_{rr}$			200			ns
Typical junction capacitance	4.0 V, 1 MHz	$C_J$			15			pF

## THERMAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	1N4933GP	1N4934GP	1N4935GP	1N4936GP	1N4937GP	UNIT
Typical thermal resistance <sup>(1)</sup>	$R_{\theta JA}$			55			$^\circ\text{C/W}$

### Note:

(1) Thermal resistance from junction to ambient and from junction to lead at 0.375" (9.5 mm) lead length, P.C.B. mounted

## ORDERING INFORMATION (Example)

PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
1N4933GP-E3/54	0.336	54	5500	13" diameter paper tape and reel
1N4933GP-E3/73	0.336	73	3000	Ammo pack packaging
1N4933GPHE3/54 <sup>(1)</sup>	0.336	54	5500	13" diameter paper tape and reel
1N4933GPHE3/73 <sup>(1)</sup>	0.336	73	3000	Ammo pack packaging

### Note:

(1) Automotive grade AEC Q101 qualified

## RATINGS AND CHARACTERISTICS CURVES

( $T_A = 25^\circ\text{C}$  unless otherwise noted)

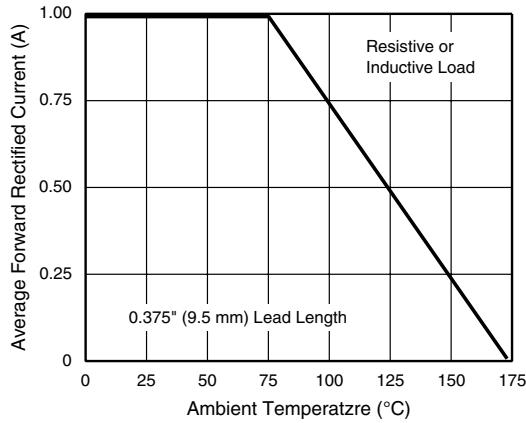


Figure 1. Forward Current Derating Curve

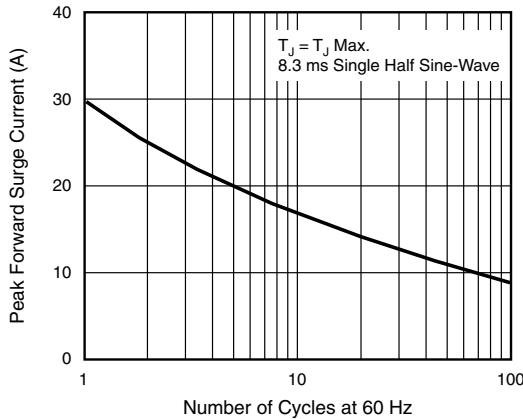
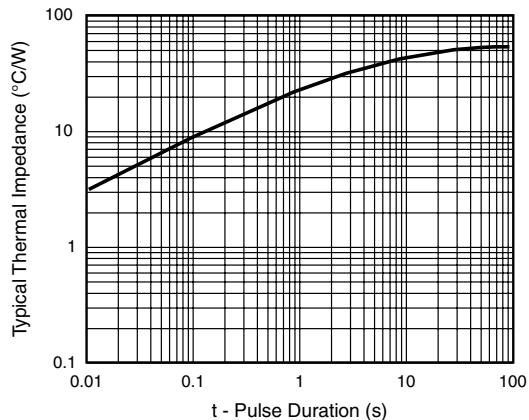
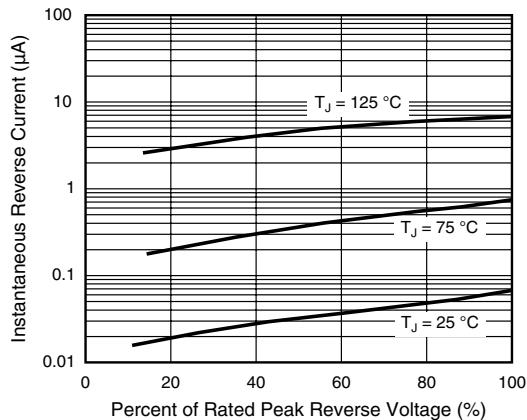
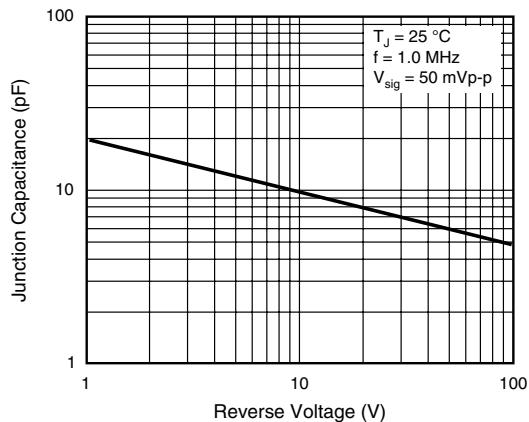
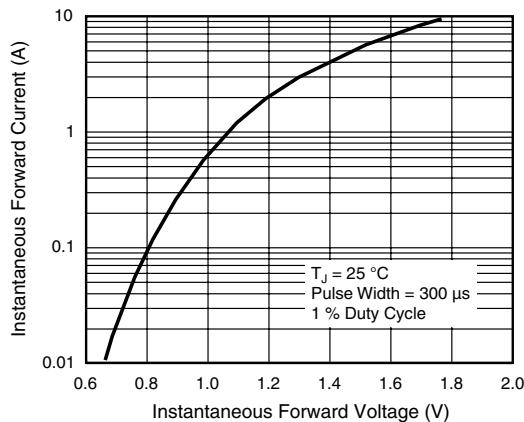
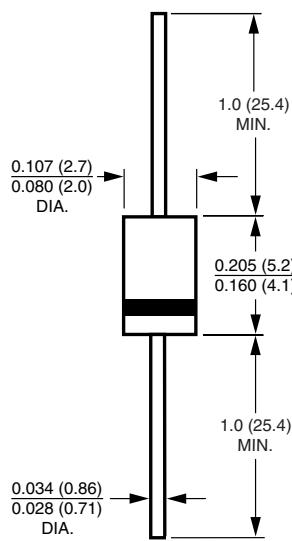


Figure 2. Maximum Non-repetitive Peak Forward Surge Current



### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

**DO-204AL (DO-41)**



Note: Lead diameter is  $\frac{0.026 \text{ (0.66)}}{0.023 \text{ (0.58)}}$  for suffix "E" part numbers